

CLASS F AMPLIFIER

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by

Tannis Hodge

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## COMMITTEE MEMBERSHIP

TITLE: Class F Amplifier

AUTHOR: Tannis Hodge

DATE SUBMITTED: June 2016

COMMITTEE CHAIR: Professor Alexander Dekhtyar, Ph.D.  
Department of Computer Science

COMMITTEE MEMBER: Associate Professor Aaron Keen, Ph.D.  
Department of Computer Science

COMMITTEE MEMBER: Professor Franz Kurfess, Ph.D.  
Department of Computer Science

## ABSTRACT

Class F Amplifier

Tannis Hodge

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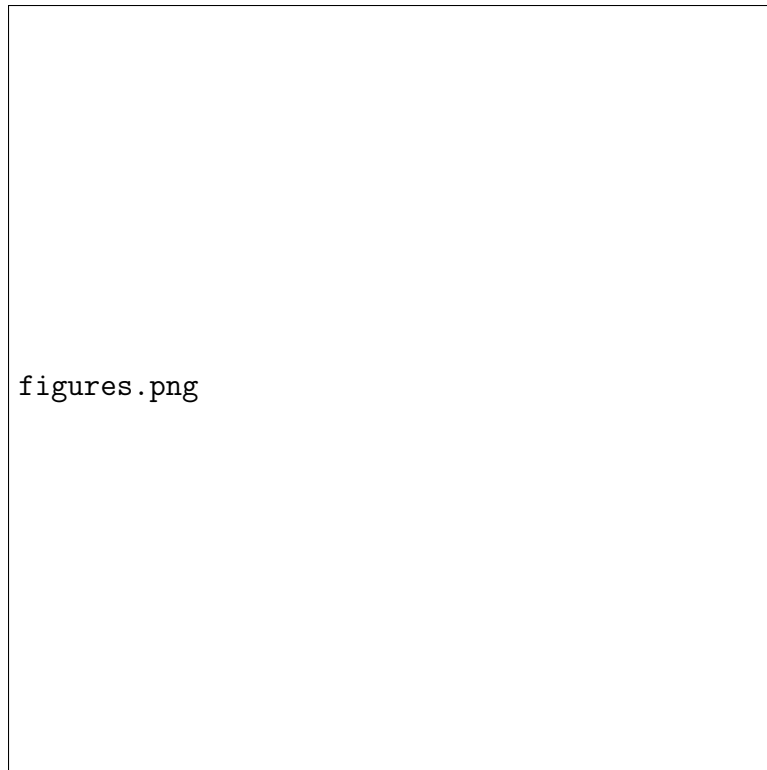
## 0.1 Amplifier Classes

The generic power amplifier consists of a transistor with a DC bias and AC coupled to the RF input and output ports. For the sake of simplicity this paper will describe the operation of FET amplifiers. The major source of power consumption of an amplifier comes from the drain source current that flows during operation. By reducing the current flow, the power added efficiency (PAE) of the amplifiers can be increased. Power amplifiers come in a variety of classes, and the most commonly used ones are A, B, AB, C, D, E, and F. Classes A through C can be described by the conduction angle of the device. The conduction angle is the amount of current flow through the transistor during a single cycle of the AC signal being amplified ranging from 0 to  $2\pi$ . For class A, the conduction angle is  $2\pi$  meaning current is always flowing when the amplifier is in

### 0.1.1 Efficiency of Amplifiers

To reduce the power consumption of a power amplifiers, two major concepts are important: zero voltage switching (ZVS) and zero voltage derivative switching (ZVDS). ZVS is when as the name implies, there is zero voltage when the amplifier is switched on and conducting so while current flows through the output no power is consumed. ZVDS is when there is no overlap between the voltage and current waveforms so no power is consumed during switching. If an amplifier can achieve ZVS and ZVDS it would theoretically be 100% efficient. A measure of amplifier efficiency is the power added efficiency (PAE) defined in equation 0.1. PAE is a measure of how efficient an amplifier is able to convert the input DC power into RF power gain. The maximum limit for a lossless system is 100%, for example if a power amplifier consumed 1 Watt and was able to output 1.001 Watt of RF power from 1 mW of RF input power, the PAE would be 100.% because all of the DC power was used to increase the RF power.

$$PAE, \% = \frac{RFPower_{out} - RFPower_{in}}{DCPower} \quad (0.1)$$



**Figure 0.1:**

### **0.1.2 Class A Amplifier**

### **0.1.3 Class B Amplifier**

### **0.1.4 Class AB Amplifier**

### **0.1.5 Class C Amplifier**

### **0.1.6 Class D Amplifier**

### **0.1.7 Class E Amplifier**

### **0.1.8 Class F Amplifier**

The class F amplifier has a theoretical efficiency of 100% through the use of multi harmonic terminations. The theory behind the class F amplifier relies on the



generation of odd voltage harmonics and shorting of even voltage harmonics at the drain of the device to increase the efficiency of the amplifier. By keeping only the odd harmonics of the signal at the output, ideally a square wave would appear and by biasing the amplifier at a conduction angle of  $\pi$  the amplifier has zero overlap between the current and voltage waveforms and no power consumed when the amplifier is switched on. The harmonics are generated due to the knee voltage of the transistor. When the AC signal causes the transistor to reach saturation the abrupt change in current flow generates voltage harmonics. In practice it becomes challenging to design matching networks as the number of harmonics to control increases. Also the output capacitance of the transistor will eventually short out higher order harmonics so 100% efficiency is not realizable in practice. By controlling up to the 5th harmonic, 90.5% efficiency can be achieved.

## 0.2 Class F Detailed Description

## 0.3 Class F Amplifier ADS Simulations, Comparisons to Specs

## 0.4 Class F Amplifier Test Results, Comparisons to Specs

## 0.5 Conclusion, Future Projects

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